

Devi Ahilya University, Indore, India Institute of Engineering & Technology				ME I Year Electronics (Sp. Digital Instrumentation) Semester- A					
Subject Code & Name			Instructions Hours per Week			Credits			
DIP2E3: Nanosensors	Nanodevices	&	L	T	P	L	T	P	Total
			Duration of Theory Paper: 3 Hours			3	1	2	3

Course Objectives: this course will focus on understanding of the basic structure principals of Nano-devices and sensors.

Prerequisite(s): Introduce the quantum mechanical concepts needed to understand the operation

COURSE CONTENTS

Unit I

Quantum Devices: Quantum Electronic devices – Electrons in mesoscopic structures – Short channel, MOS Transistor – split Gate Transistor – Electron wave transistor – Electron spin transistor – Quantum Dot array – Quantum computer- Bit and Qubit. Carbon Nanotube based logic gates, optical devices. . Connection with quantum dots, quantum wires, and quantum wells

Unit II

Tunneling Devices: Tunnelling element – Tunnel Effect and Tunneling Elements-Tunneling Diode – Resonant Tunneling Diode – Three -Terminal Resonate Tunneling Devices-Technology of RTD-Digital circuits design based on RTDs - Basics Logic Circuits – Single Electron Transistor(SET) – Principle – Coulomb Blockade-Performance – Technology- Circuit Design- Logic and Memory Circuits – SET adder as an Example of a Distributed Circuit.

Unit III

Nanosensors I: Micro and nano-sensors, Fundamentals of sensors, biosensor, micro fluids, Packaging and characterization of sensors, Method of packaging at zero level, dye level and first level. Sensors for aerospace and defense: Accelerometer, Pressure Sensor, Night Vision System, Nano tweezers, nano-cutting tools, Integration of sensor with actuators and electronic circuitry,

Unit IV

Nanosensors II: Sensor for bio-medical applications: Cardiology, Neurology and as diagnostic tool, For other civil applications: metrology, bridges etc. Biosensors. Clinical Diagnostics, generation of biosensors, immobilization, characteristics, applications, conducting Polymer based sensor, DNA Biosensors, optical sensors. Biochips. Metal Insulator Semiconductor devices, molecular electronics, information storage, molecular switching, Schottky devices,

Unit V

NEMS: Inertial sensors – accelerometer – gyroscope - micromechanical pressure sensors – pizoresistive – capacitive - microrobotics – micro channel heat sinks – optical MEMS – visual display – precision optical platform – optical data switching – RF MEMS – MEMS variable capacitors – MEMS switches – Resonators.

Test Books and Reference Books:

- [1] K. Goser, P. Glosekotter and J. Dienstuhl, “Nanoelectronics and Nanosystems-From Transistors to Molecular Quantum Devices”, Springer, 2004.
- [2] HerveRigneault, Jean-Michel Lourtioz, Claude Delalande, Ariel Levenson, “Nanophotonics”, ISTE.
- [3] W.R.Fahrner, “Nanotechnology and Nanoelectronics – Materials, Devices and Measurement Techniques” Springer, 2006 13
- [4] Sensors: Micro &Nanosensors, Sensor Market trends (Part 1&2) by H. Meixner.
- [5] Nanoscience& Technology: Novel structure and phenomena by Ping Sheng (Editor)
- [6] Nano Engineering in Science &Technology : An introduction to the world of nano design by Michael Rieth.
- [7] Tai –Ran Hsu, “MEMS & Microsystems Design and Manufacture”, Tata McGraw-Hill publication, 2001.
- [8] P. Rai-Choudhury, “MEMS and MOEMS technology and applications”, PHI learning private Ltd, 2009.
- [9] Mohamed Gad-el-Hak, “The MEMS Handbook”, CRC Press, 2002.